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April 1st, 2010 Rene<mark>sas E</mark>lectronics Corporation

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HA12231FP

Audio Signal Processor for Car Deck (PB 1 Chip)

REJ03F0135-0200

Previous: ADE-207-327A

Rev.2.00 Jun 15, 2005

Description

HA12231FP is silicon monolithic bipolar IC providing PB equalizer system and music sensor system in one chip.

Functions

• PB equalizer × 2 channel

• Music sensor × 1 channel

• Line amp. × 2 channel

• Line mute × 2 channel

Features

- No use external parts for PB equalizer. (Fixed characteristics built-in)
- Available to change music sensing level by external resistor.
- Available to change frequency response of music sensor by external capacitor.
- Different type of PB equalizer characteristics selection (120 μs/70 μs) is available.
- Line mute ON/OFF is available.
- This IC is strong for a cellular phone noise.

Ordering Information

Product	Package Code (Previous Code)	PBOUT-Level	Functions PB-EQ	Music Sensor	Mute
HA12231FP	PRSP0020DD-A (FP-20DA)	450 mVrms	O	О	Э

Pin Description, Equivalent Circuit

 $(V_{CC} = 9 \text{ V}, \text{ A system of single supply voltage}, \text{Ta} = 25^{\circ}\text{C}, \text{ No Signal}, \text{ The value in the table shows typical value.})$

Pin No.	Pin Name	Note	Equivalent Circuit	Description
16	TAI(L)	$V = V_{CC}/2$	<u></u>	Tape input
5	TAI(R)		•	
			VOI	
			100 k≶	
			V _{CC} /2	
14	RIP	$V = V_{CC}/2$	Vcc	Ripple filter
			$\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ $	
			V	
			\$ \$\frac{1}{2}	
			GND	
13	MS DET	$V = V_{CC}$	\wedge	Time constant pin for
				rectifier
			The state of the s	
			GND	
		N N 15		
15	PBOUT(L)	$V = V_{CC}/2$	Vcc	PB output
6	PBOUT(R)		*	
			V \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	
			*	
			₹ GND	
1	VREF	$V = V_{CC}/2$	V _{CC}	Reference output
17	EQOUT(L)	$V = V_{CC}/2$	Vcc	Equalizer output (120 μ)
4	EQOUT(R)			
			v T	
		_	¥	
			<i>\\</i>	
			₹ GND	
11	V _{CC}			Power supply
19	FIN(L)	_		Equalizer input
18	RIN(L)	1	\bigoplus	-1
3	RIN(R)	1		
2	FIN(R)	1	V \(\frac{1}{2} \)	

Note: MS: Music Sensor

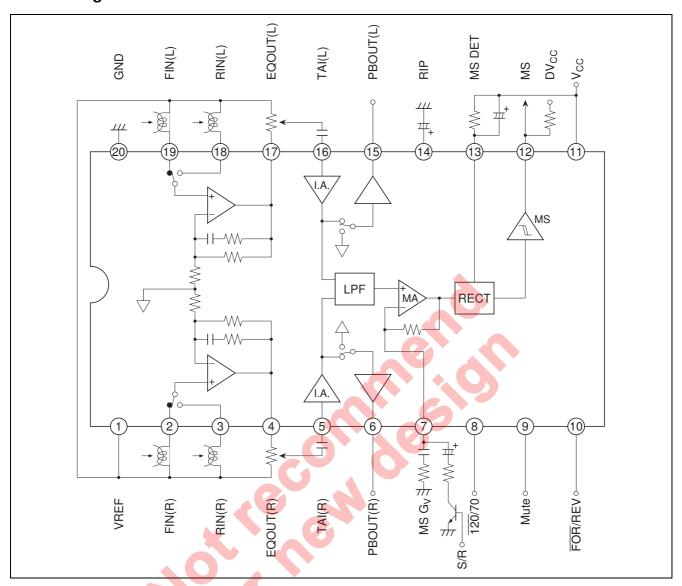
Pin Description, Equivalent Circuit (cont.)

 $(V_{CC} = 9 \text{ V}, \text{ A system of single supply voltage, } Ta = 25^{\circ}\text{C}, \text{ No Signal, } The value in the table shows typical value.)}$

Pin No.	Pin Name	Note	Equivalent Circuit	Description
9	Mute	_	* *	Mode control input
10 8	FOR/REV 120/70		22 k §	
			100 k GND	
12	MS		200 \$\frac{100 \text{ k}}{200 \text{ P}} D GND	MS output (to MPU) *
7	MS G _V	V = V _{CC} /2		MS gain pin *
			V	
20	GND	_		GND pin
Note: MS	S: Music Sensor			



Block Diagram



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Rating	Unit	Note
Supply voltage	V _{CC} Max	15	V	
Power dissipation	Pd	400	mW	Ta ≤ 85°C
Operating temperature	Topr	-40 to +85	°C	
Storage temperature	Tstg	-55 to +125	°C	

		Test Condition		ion					A	pplica	tion 1	Гегті	nal					
			IC Cor	ndition			Spe	Specification		cification			In	out	Out	put		
Item	Symbol	INPUT	OUTPUT	fin(Hz)	PBOUT level(dB)	Other	Min	Тур	Max	Unit	R	٦	R	L		Re- mark		
Quiescent current	IQ	_	_	_	_	No signal	<u> </u>	6.0	9	mA	_	_	_	_	11			
Input AMP. gain	G _V IA	TAI	PBOUT	1k	0		22.5	23.5	24.5	dB	5	16	6	15	_			
Signal handling	Vomax	TAI	PBOUT	1k	_	THD = 1%	12.0	13.0	_	dB	5	16	6	15	_	*1		
T.H.D.	THD	TAI	PBOUT	1k	0		_	0.05	0.3	%	5	16	6	15	_			
Channel separation	CT RL	FIN	PBOUT	1k	12		50.0	60.0	_	dB	2	19	6→ 15	15→ 6				
PB-EQ gain	G _V EQ 1k	FIN/RIN	EQOUT	1k	0	120μs	37.0	40.0	43.0	dB	2/3	19/18	4	17				
	G _V EQ 10k(1)	FIN	EQOUT	10k	0	120μs	33.0	36.0	39.0	dB	2	19	4	17				
	G _V EQ 10k(2)	FIN	EQOUT	10k	0	70μs	29.0	32.0	35.0	dB	2	19	4	17				
PB-EQ maximum output	V _{OM}	FIN/RIN	EQOUT	1k	_	THD = 1%	300	600	_	mVrms	2/3	19/18	4	17	ı	*1		
PB-EQ THD	THD-EQ	FIN/RIN	EQOUT	1k	0		_	0.1	0.5	%	2/3	19/18	4	17	_			
Noise voltage level converted in input	VN	FIN/RIN	EQOUT	(1k)	(0)	Rg = 680Ω , Din-Audio Filter	_	1.2	2.0	μVrms	2/3	19/18	4	17	_			
MS sensing level	V _{ON}	TAI	PBOUT MSOUT	5k	_		-18.0	-14.0	-10.0	dB	5	16	6	15	12			
MS output low level	V _{OL}	TAI	PBOUT MSOUT	5k	0		_	1.0	1.5	V	5	16	6	15	12			
MS output leak current	I _{OH}		MSOUT		_	No signal	_	0.0	2.0	μА	_	_	12	12	_			
MUTE attenuation	Mute	TAI	PBOUT	1k	12		70.0	80.0	_	dB	5	16	6	15	_			
Control voltage	V _{IL}			_			-0.2	_	1.0	V	_		_	_	8, 9,			
	V _{IH}			4			3.5	_	V_{CC}						10			
Note: 1. V _{CC} = 7.2 V				0/6														



Test Circuit

EQ PB SW8 <u>₩</u> \$R11 \$10k TAI C11 _{μμ} 0.47μ+ SW3^ORIN DC SOURCE1 R10 10k≶ R13 C12 5.1k 0.1μ R14 680 R12 5.1k C9 1μ+ $\begin{array}{c} C8 \\ 0.33\mu \end{array}$ $\stackrel{R9}{=}$ $\stackrel{330k}{=}$ SW6 ₹R8 \$3.9k #C7 100μ C10 ₋₋₋ 2.2μ+ MS SW13 DC VM PBR^O MS DET SM \MS RECT FOR/REV 120/70 FIN(R) VREF SW9 120 OFF C6⊥ 0.01μ⊤ ON R4≤ C3 5.1k 0.1μ R6 10k R7≤ 24k≤ • <u>REV</u> •EXT SW11 FOR AC VM2 DC SOURCE2 Distortion SW4 C4 0.47μ[±] analyzer DC SOURCE3 Oscillo °TAI Lch ≶R5 10k scope Lch SW12 SW2 PB SW7 Noise ON OFF SW1 meter Rch EQ NOISE METER WITH CCIR/ARM FILTER AND DIN/AUDIO FILTER AC VM1 AUDIO SG Notes: 1. Resistor tolerance $\pm 1\%$ 2. Capacitor tolerance $\pm 1\%$ 3. Unit R: Ω , C: F

Functional Description

Power Supply Range

HA12231FP is designed to operate on single supply only.

Table 1 Supply Voltage Range

Product	Single Supply
HA12231FP	7.2 V to 12.0 V

Reference Voltage

HA12231FP provides the reference voltage of half the supply voltage that is the signal grounds. As the peculiarity of this device, the capacitor for the ripple filter is very small about 1/100 compared with their usual value. The block diagram is shown as figure 1.

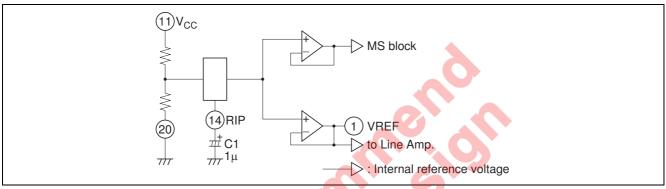


Figure 1 The Block Diagram of Reference Supply Voltage

Operating Mode Control

HA12231FP provides fully electronic switching circuits. And each operating mode control are controlled by parallel data (DC voltage).

When a power supply of this IC is cut off, for a voltage, in addition to a mode control terminal even though as do not destruct it, in series for resistance.

Table 2 Threshold Voltage (V_{TH})

Pin No.	Lo	Hi	Unit	Test Condition			
8, 9, 10	-0.2 to 1.0	3.5 to V _{CC}	V	Input Pin Measure			

Table 3 Switching Truth Table

Pin No.	Pin Name	Low	High			
8	120/70	120 μ (Normal)	70 μ (Metal or Chrome)			
9	Mute	Mute OFF	Mute ON			
10	FOR/REV	Forward	Reverse			

Notes: 1. Each pins are on pulled down with 100 k Ω internal resistor. Therefore, it will be low-level when each pins are open.

- 2. Over shoot level and under shoot level of input signal must be the standardized. (High: V_{CC} , Low: $-0.2\ V$)
- 3. Reducing pop noise is so much better for 10 k Ω to 22 k Ω resisitor and 1 μ F to 22 μ F capacitor shown figure 2.

Input Pin 10 to 22 k
$$\Omega$$
 \longrightarrow MPU \longrightarrow 1 to 22 μ F

Figure 2 Interface for Reduction of Pop Noise

Input Block Diagram and Level Diagram

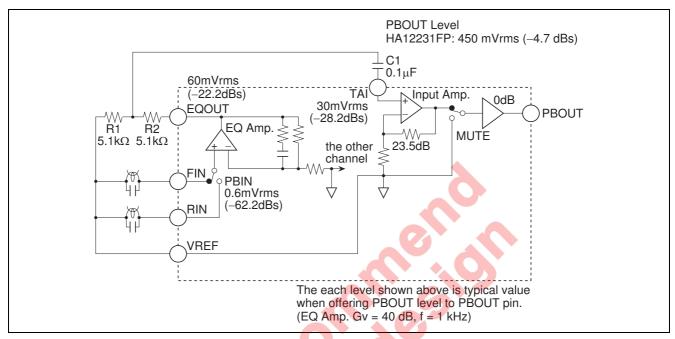


Figure 3 Input Block Diagram

Adjustment of Playback Reference Operate Level

After replace R1 and R2 with a half-fix volume of $10 \text{ k}\Omega$, adjust playback reference operate level.

The Sensitivity Adjustment of Music Sensor

Adjusting MS Amp. gain by external resistor, the sensitivity of music sensor can set up. The music sensor block diagram is shown in figure 4, and frequency response is shown in figure 5.

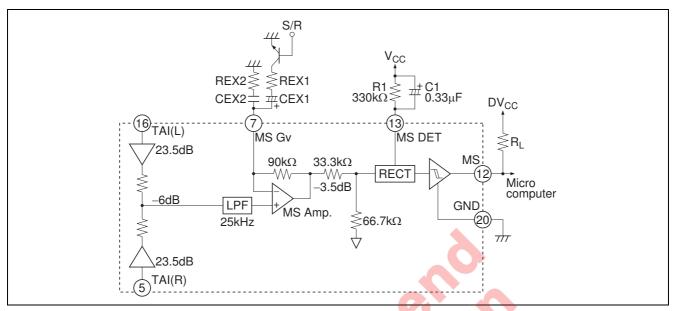


Figure 4 Music Sensor Block Diagram

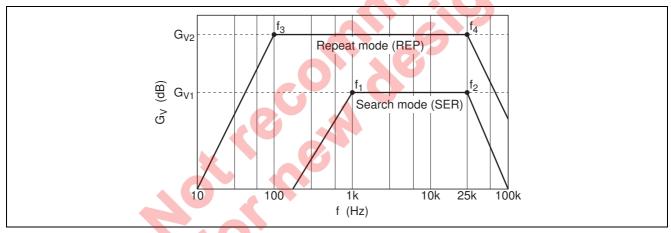


Figure 5 Frequency Response

1. Search mode

$$\begin{split} G_{V1} &= (23.5 \text{dB} - 3.5 \text{dB}) + 20 \text{log} \left(1 + \frac{90 \text{k}}{\text{REX2}} \right) \quad \text{[dB]} \\ f_1 &= \frac{1}{2 \pi \cdot \text{CEX2} \cdot \text{REX2}} \quad \text{[Hz]}, \; \; f_2 = 25 \text{k} \; \; \text{[Hz]} \end{split}$$

2. Repeat mode

$$\begin{aligned} G_{V2} &= (23.5 dB - 3.5 dB) + 20 log \left(1 + \frac{90 k}{REX1}\right) \quad [dB] \\ f_3 &= \frac{1}{2\pi \cdot CEX1 \cdot REX1} \quad [Hz], \; f_4 = 25 k \; [Hz] \end{aligned}$$

The sensitivity of music sensor (S) is computed by the formula mentioned below.

$$S=12.7-G_V\quad \text{[dB]}$$

S is 6 dB down in case of one-side channel.

Notes: 1. Search mode: G_{V1} , Repeat mode: G_{V2}

- 2. Standard level of TAI pin (Dolby level correspondence) = 30 mVrms
- 3. Standard sensing level of music sensor = 130 mVrms

							S	S
							(one side	(both
Item	REX1, 2	CEX1, 2	G _{V1, 2}	f _{1,3}		f _{2, 4}	channel)	channel)
Search mode	24 kΩ	0.01 μF	33.5 dB	663 Hz	25	kHz	-14.8 dB	–20.8 dB
Repeat mode	2.4 kΩ	1 μF	51.7 dB	66.3 Hz	25	kHz	–33.0 dB	–39.0 dB

Note: This MS presented hysteresis lest MS(OUT) terminal should turn over again High level or Low level, in case of thresh S level constantly.

Music Sensor Time Constant

- 1. Sensing no signal to signal (Attack) is determined by C1, 0.01 μF to 1 μF capacitor C1 can be applicable.
- 2. Sensing signal to no signal (Recovery) is determined by C1 and R1, however preceding (1), $100 \text{ k}\Omega$ to $1 \text{ M}\Omega$ can be applicable.

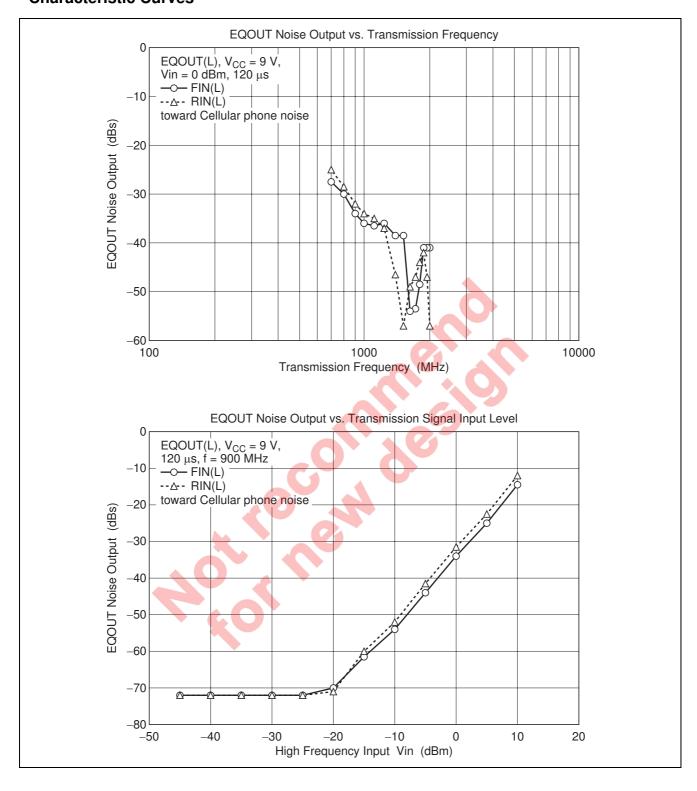
Music Sensor Output (MS(OUT))

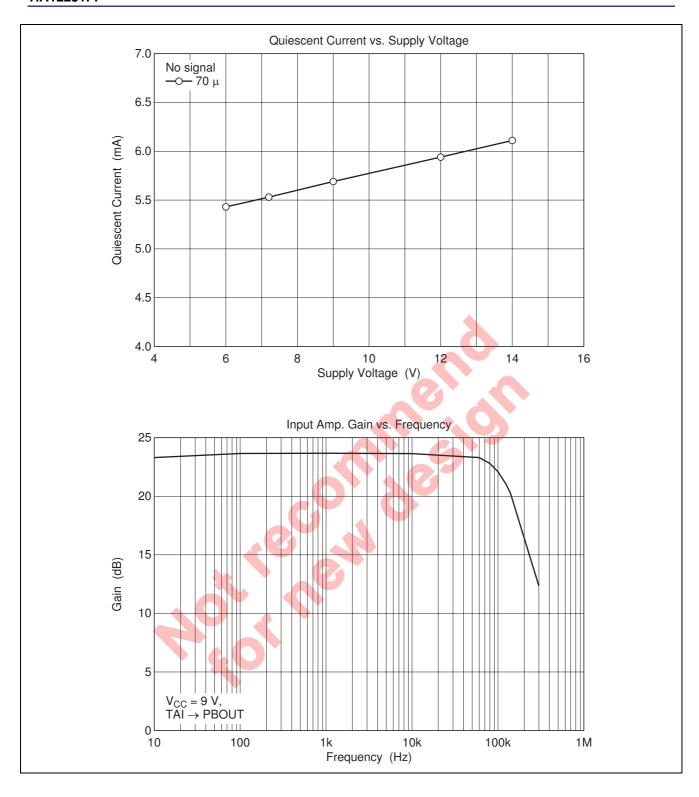
As for the internal circuit of music sensor block, music sensor output pin is connected to the collector of NPN type directly, therefore, output level will be "high" when sensing no signal. And output level will be "low" when sensing signal.

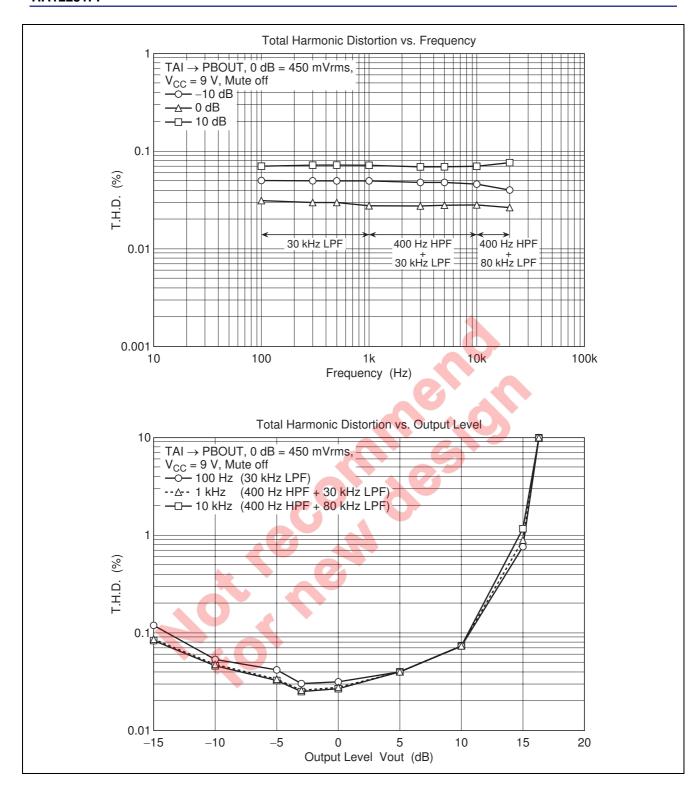
$$I_{L} = \frac{DV_{CC} - MS(OUT)_{LO}^{*}}{R_{L}}$$
* MS(OUT)_{LO} : Sensing signal (about 1V)

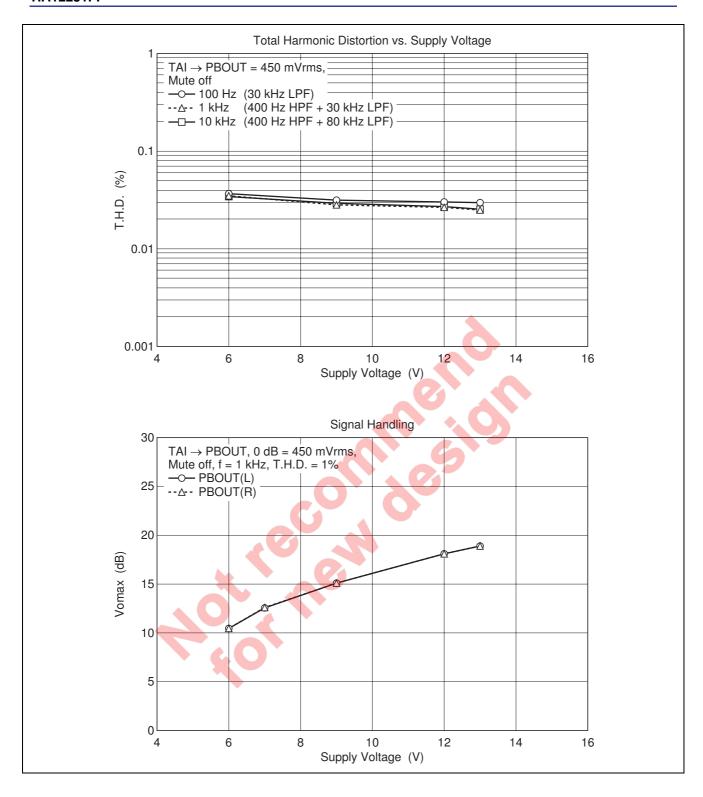
Note: Supply voltage of MS (OUT) pin must be less than V_{CC} voltage.

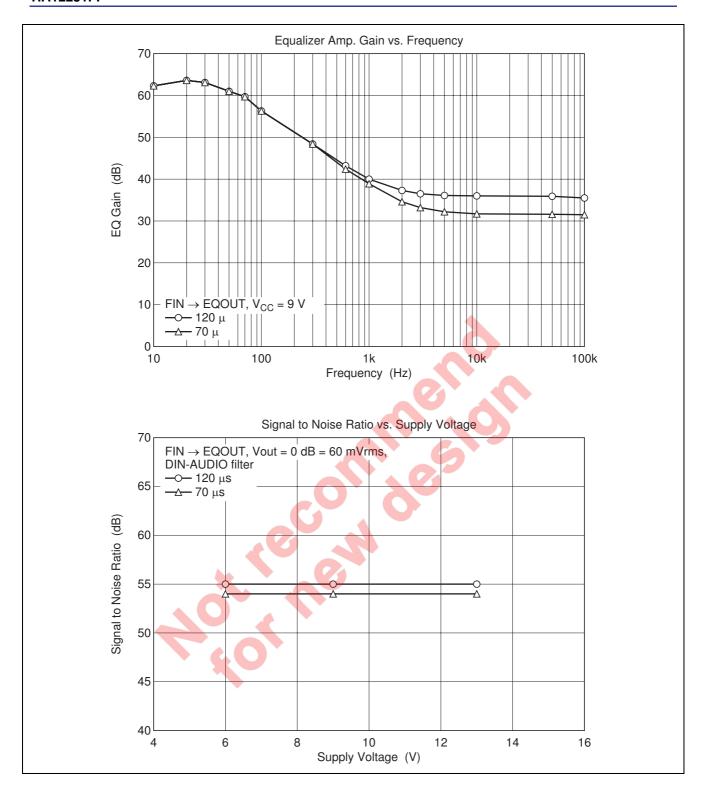
Characteristic Curves

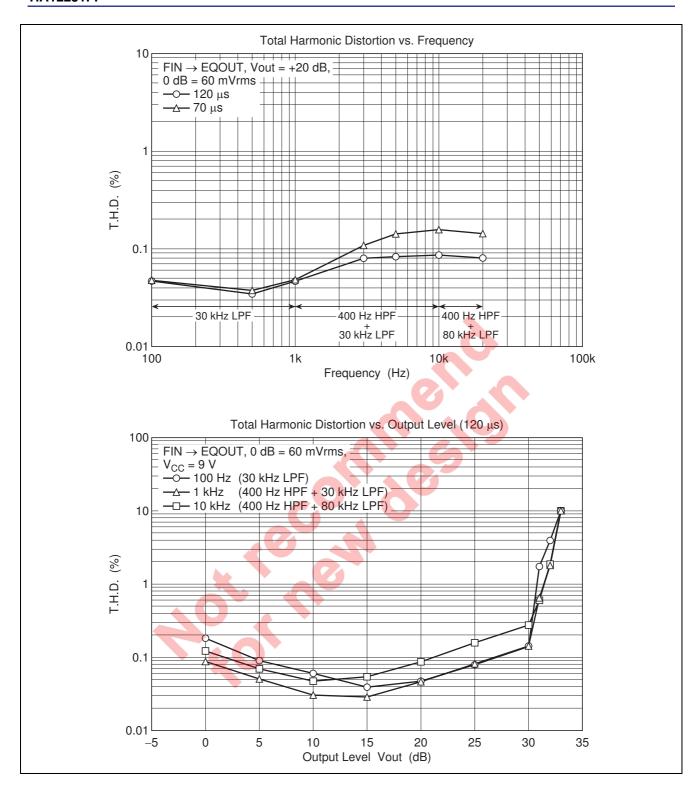


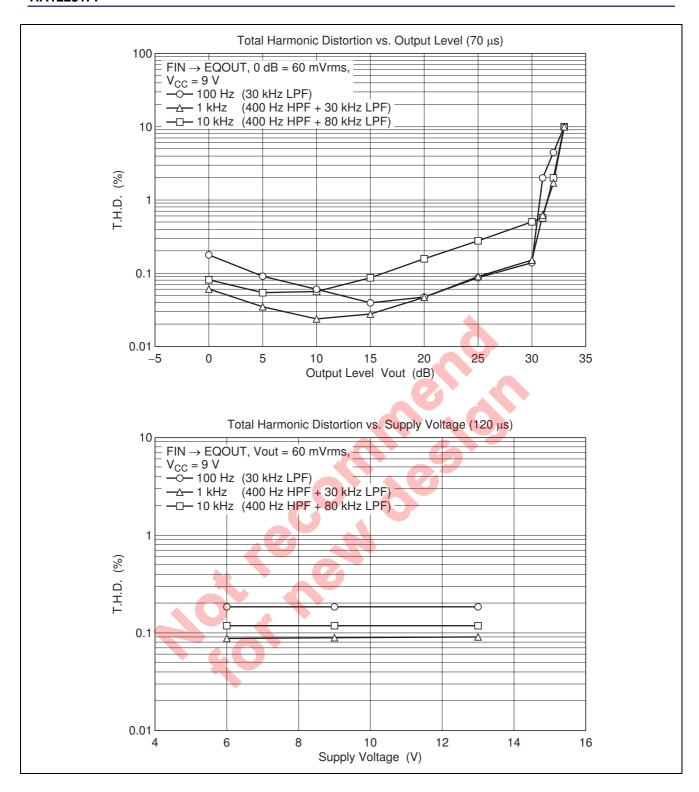


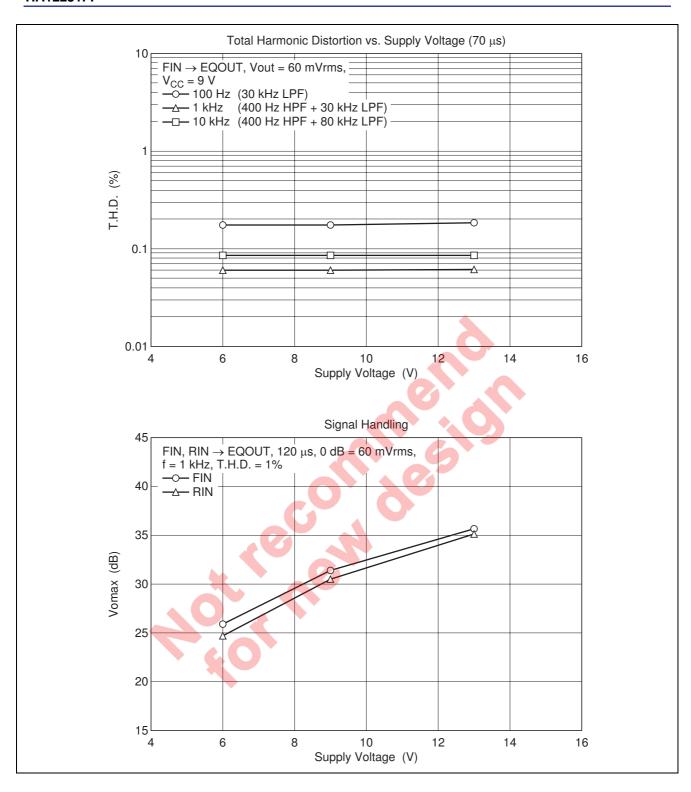


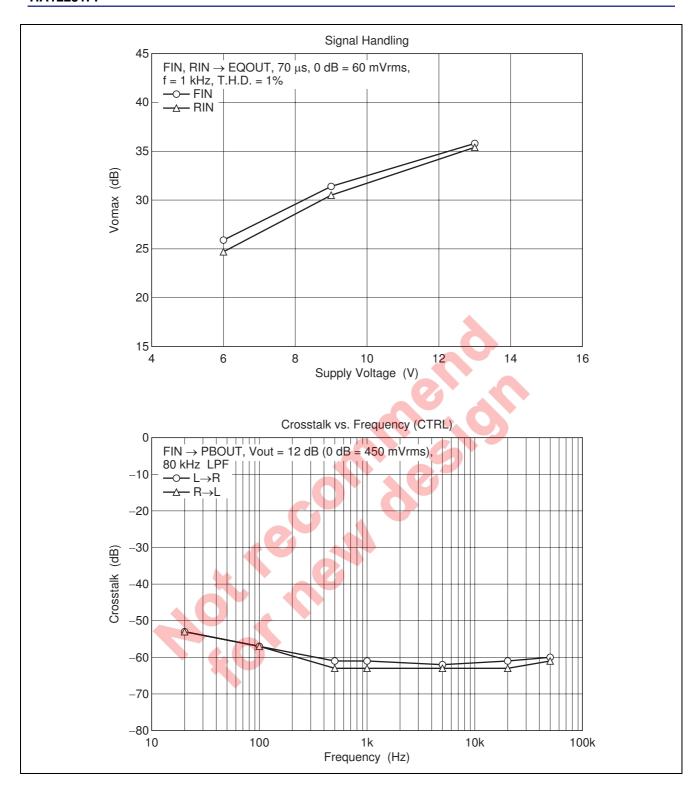


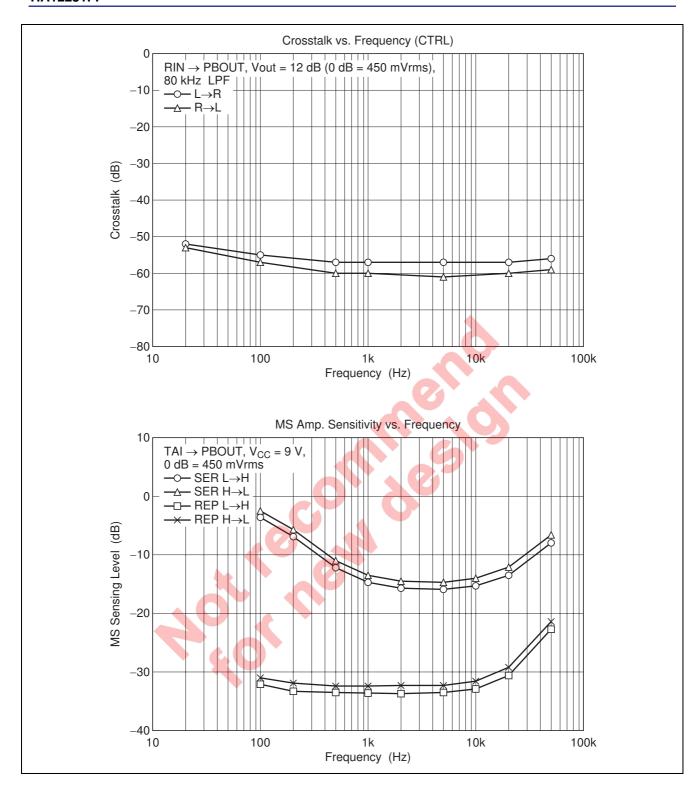


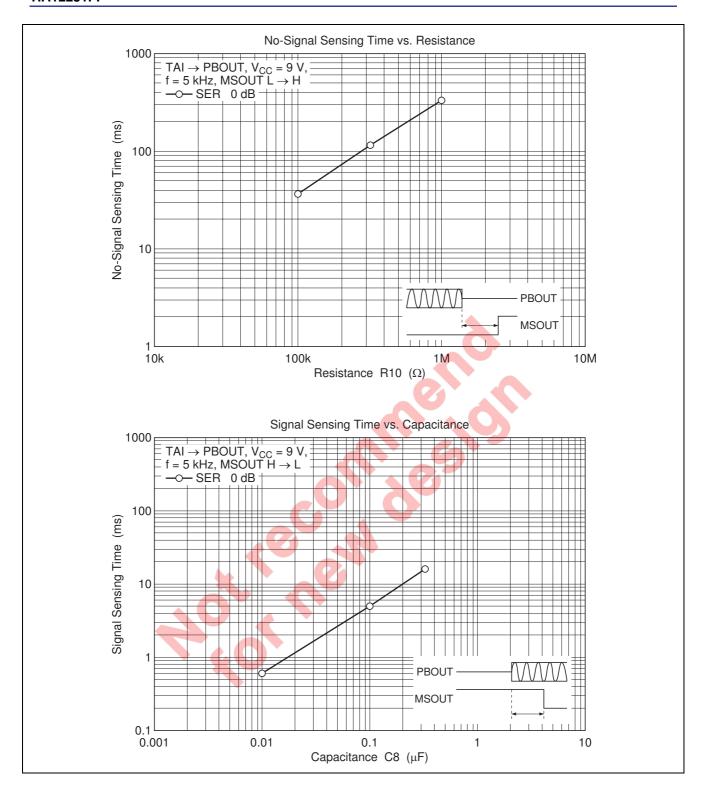




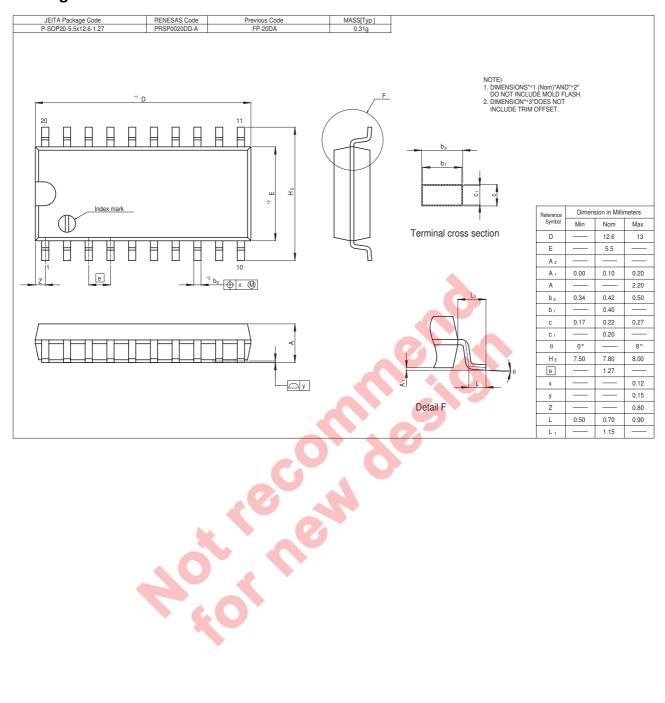








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